

Amplifier Transistors

MAXIMUM RATINGS

Rating	Symbol	MPS8098 MPS8598	MPS8099 MPS8599	Unit
Collector–Emitter Voltage	V_{CE0}	60	80	Vdc
Collector–Base Voltage	V_{CB0}	60	80	Vdc
Emitter–Base Voltage	V_{EB0}	6.0	5.0	Vdc
Collector Current – Continuous	I_C	500		mAdc
Total Device Dissipation @ $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	625	5.0	mW mW/ $^\circ\text{C}$
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D	1.5	12	Watts mW/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	T_J, T_{stg}	–55 to +150		$^\circ\text{C}$

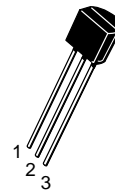
THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	200	$^\circ\text{C}/\text{W}$
Thermal Resistance, Junction to Case	$R_{\theta JC}$	83.3	$^\circ\text{C}/\text{W}$

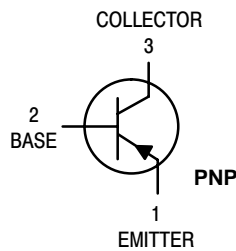
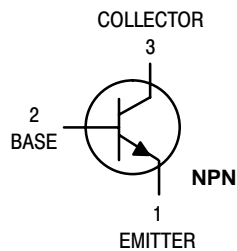
NPN
MPS8098
MPS8099*
PNP
MPS8598
MPS8599*

Voltage and current are negative
for PNP transistors

*ON Semiconductor Preferred Device



CASE 29–11, STYLE 1
TO–92 (TO–226AA)



Preferred devices are ON Semiconductor recommended choices for future use and best overall value.

NPN MPS8098 MPS8099 PNP MPS8598 MPS8599

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERISTICS					
Collector–Emitter Breakdown Voltage ⁽¹⁾ (I _C = 10 mA _{dc} , I _B = 0)	MPS8098, MPS8598 MPS8099, MPS8599	V _{(BR)CEO}	60 80	— —	V _{dc}
Collector–Base Breakdown Voltage (I _C = 100 μA _{dc} , I _E = 0)	MPS8098, MPS8598 MPS8099, MPS8599	V _{(BR)CBO}	60 80	— —	V _{dc}
Emitter–Base Breakdown Voltage (I _E = 10 μA _{dc} , I _C = 0)	MPS8098, MPS8099 MPS8598, MPS8599	V _{(BR)EBO}	6.0 5.0	— —	V _{dc}
Collector Cutoff Current (V _{CE} = 60 V _{dc} , I _B = 0)		I _{CES}	—	0.1	μA _{dc}
Collector Cutoff Current (V _{CB} = 60 V _{dc} , I _E = 0) (V _{CB} = 80 V _{dc} , I _E = 0)	MPS8098, MPS8598 MPS8099, MPS8599	I _{CBO}	— —	0.1 0.1	μA _{dc}
Emitter Cutoff Current (V _{EB} = 6.0 V _{dc} , I _C = 0) (V _{EB} = 4.0 V _{dc} , I _C = 0)	MPS8098, MPS8099 MPS8598, MPS8599	I _{EBO}	— —	0.1 0.1	μA _{dc}

1. Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle = 2.0%.

ON CHARACTERISTICS⁽¹⁾

DC Current Gain (I _C = 1.0 mA _{dc} , V _{CE} = 5.0 V _{dc}) (I _C = 10 mA _{dc} , V _{CE} = 5.0 V _{dc}) (I _C = 100 mA _{dc} , V _{CE} = 5.0 V _{dc})		h _{FE}	100 100 75	300 — —	—
Collector–Emitter Saturation Voltage (I _C = 100 mA _{dc} , I _B = 5.0 mA _{dc}) (I _C = 100 mA _{dc} , I _B = 10 mA _{dc})		V _{CE(sat)}	— —	0.4 0.3	V _{dc}
Base–Emitter On Voltage (I _C = 1.0 mA _{dc} , V _{CE} = 5.0 V _{dc}) (I _C = 10 mA _{dc} , V _{CE} = 5.0 V _{dc})	MPS8098, MPS8598 MPS8099, MPS8599	V _{BE(on)}	0.5 0.6	0.7 0.8	V _{dc}

SMALL–SIGNAL CHARACTERISTICS

Current–Gain — Bandwidth Product (I _C = 10 mA _{dc} , V _{CE} = 5.0 V _{dc} , f = 100 MHz)		f _T	150	—	MHz
Output Capacitance (V _{CB} = 5.0 V _{dc} , I _E = 0, f = 1.0 MHz)	MPS8098, MPS8099 MPS8598, MPS8599	C _{obo}	— —	6.0 8.0	pF
Input Capacitance (V _{EB} = 0.5 V _{dc} , I _C = 0, f = 1.0 MHz)	MPS8098, MPS8099 MPS8598, MPS8599	C _{ibo}	— —	25 30	pF

1. Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle = 2.0%.

NPN MPS8098 MPS8099 PNP MPS8598 MPS8599

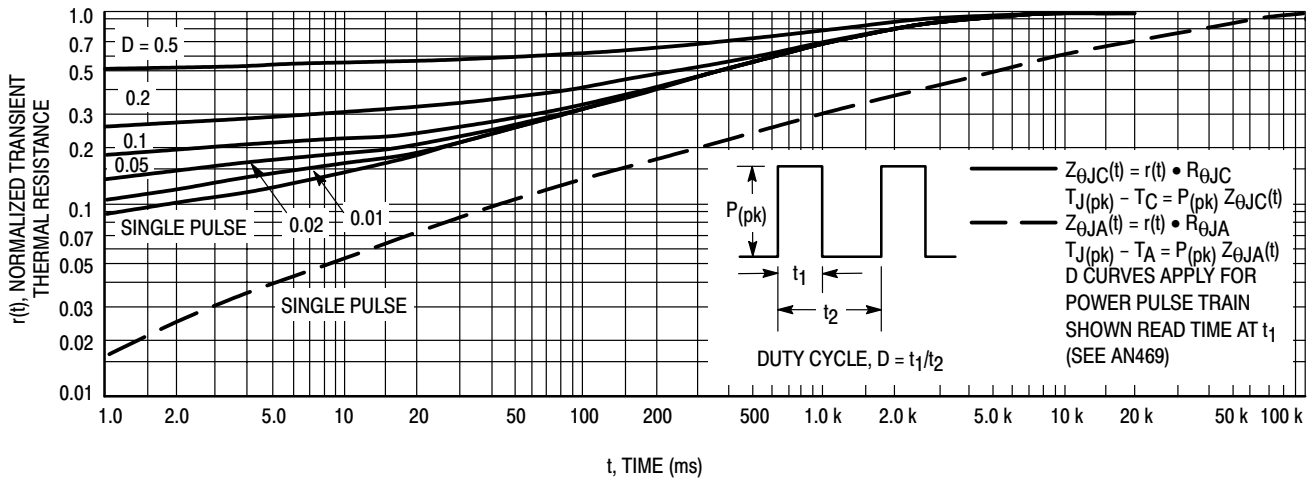
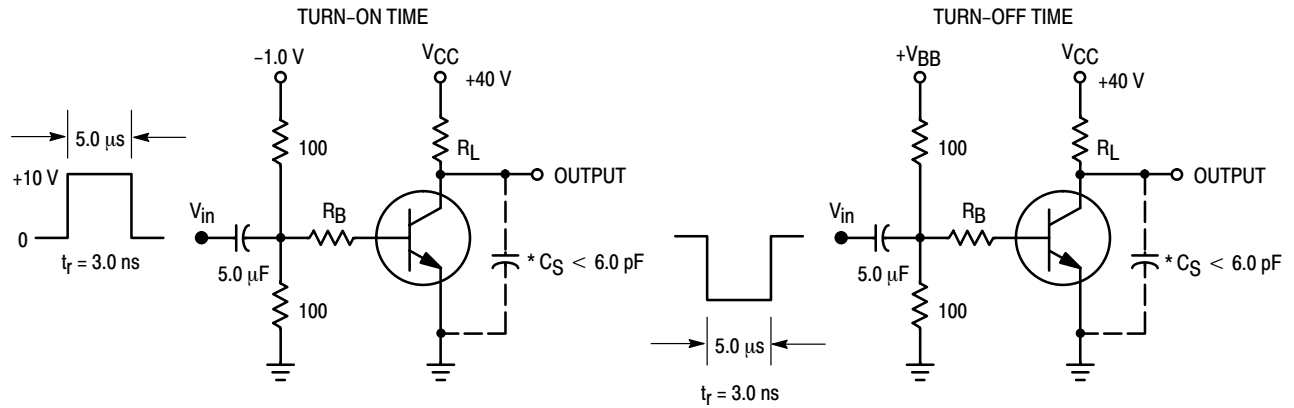


Figure 1. MPS8098, MPS8099, MPS8598 and MPS8599 Thermal Response



*Total Shunt Capacitance of Test Jig and Connectors
For PNP Test Circuits, Reverse All Voltage Polarities

Figure 2. Switching Time Test Circuits

NPN MPS8098 MPS8099 PNP MPS8598 MPS8599

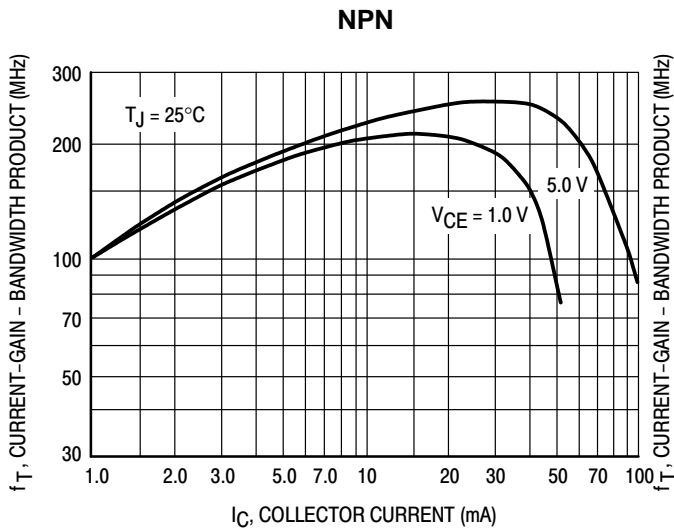


Figure 3. MPS8098/99 Current-Gain — Bandwidth Product

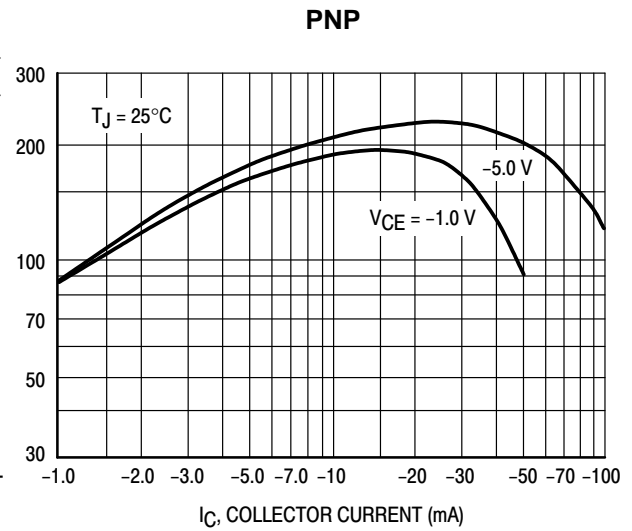


Figure 4. MPS8598/99 Current-Gain — Bandwidth Product

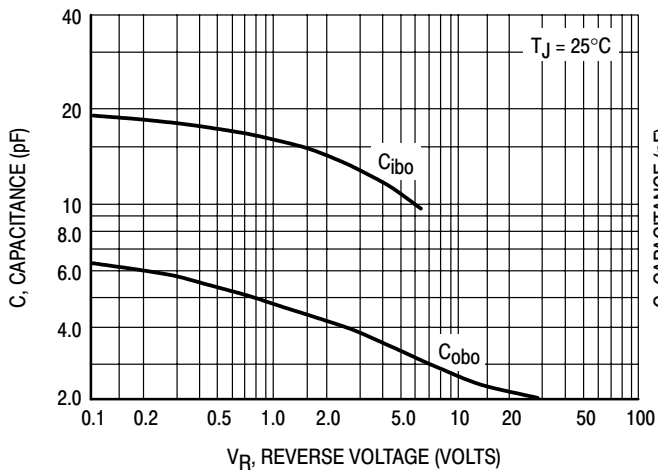


Figure 5. MPS8098/99 Capacitance

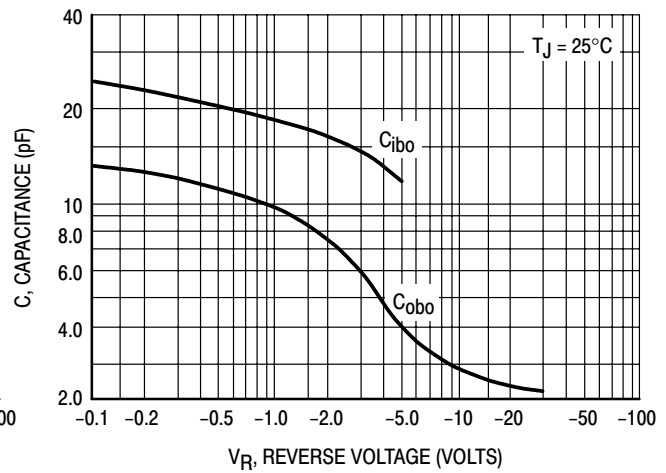


Figure 6. MPS8598/99 Capacitance

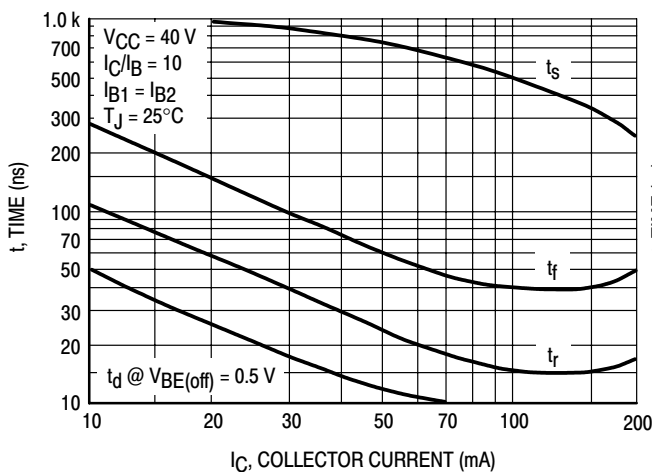


Figure 7. MPS8098/99 Switching Times

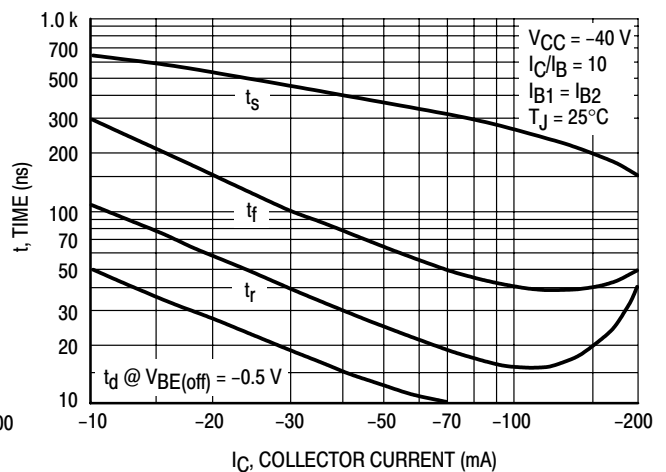


Figure 8. MPS8598/99 Switching Times

NPN MPS8098 MPS8099 PNP MPS8598 MPS8599

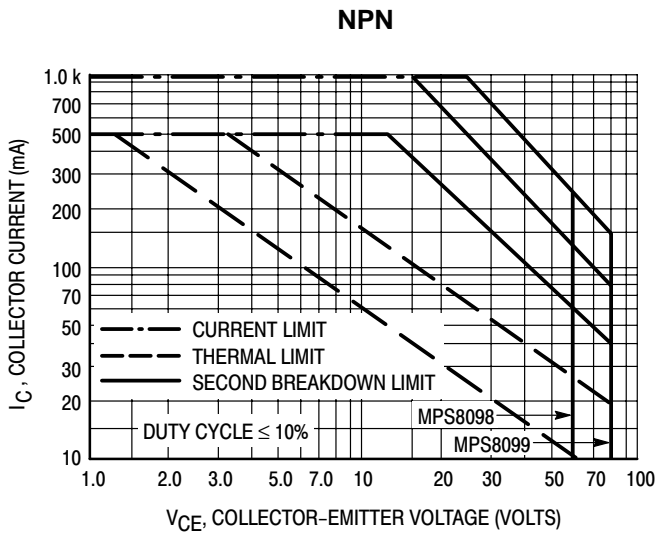


Figure 9. MPS8098/99 Active-Region Safe Operating Area

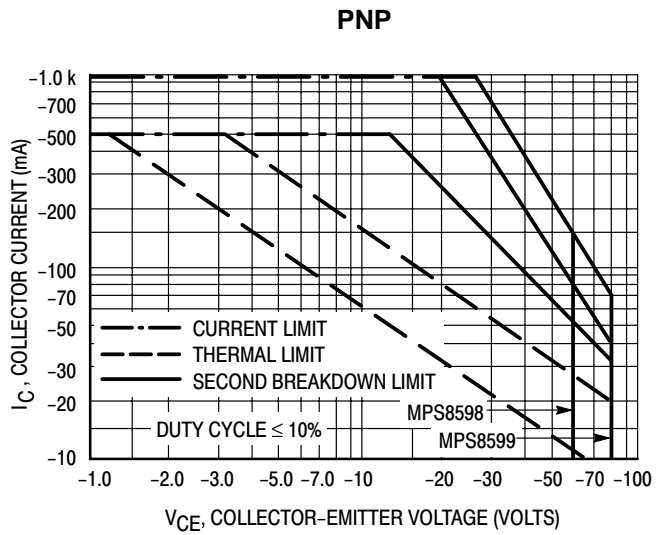


Figure 10. MPS8598/99 Active-Region Safe Operating Area

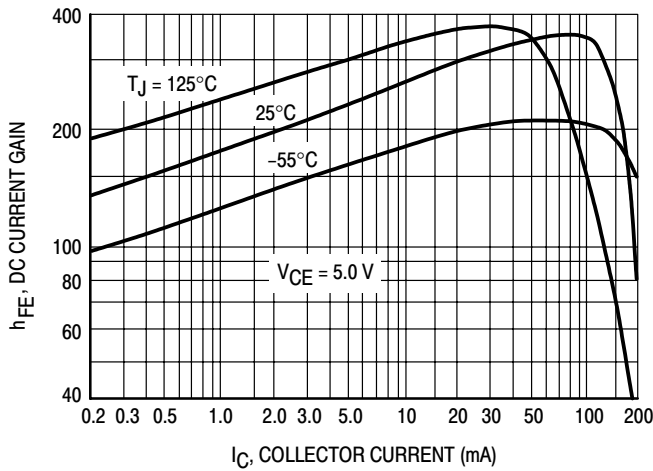


Figure 11. MPS8098/99 DC Current Gain

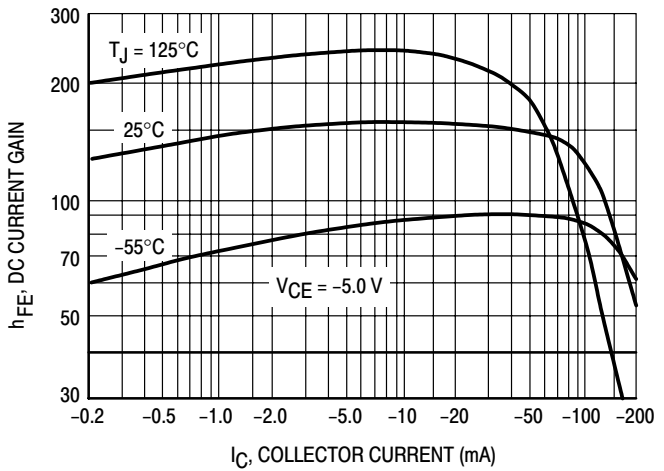


Figure 12. MPS8598/99 DC Current Gain

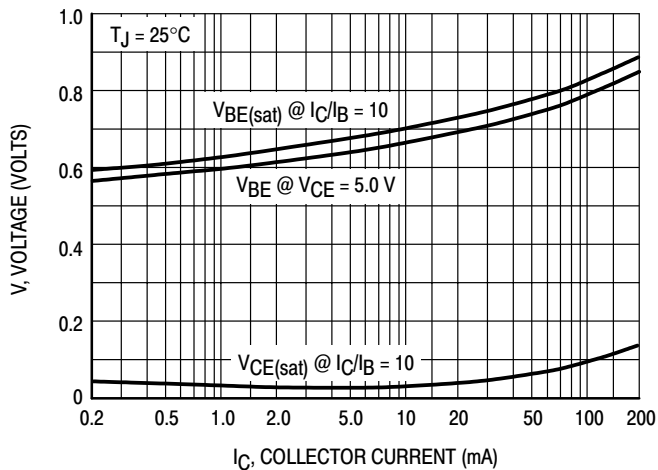


Figure 13. MPS8098/99 "ON" Voltages

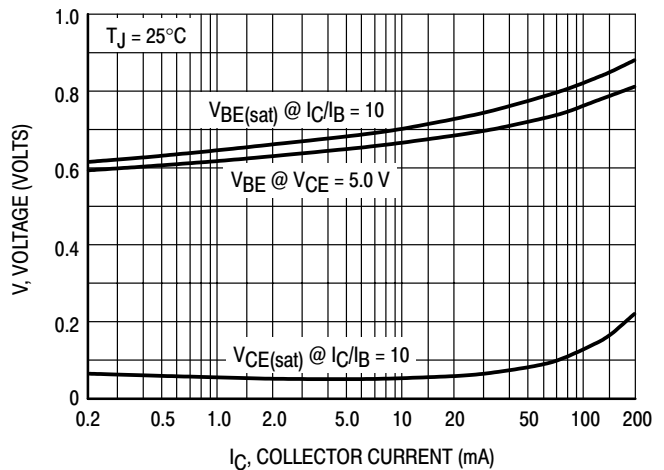


Figure 14. MPS8598/99 "ON" Voltages

NPN MPS8098 MPS8099 PNP MPS8598 MPS8599

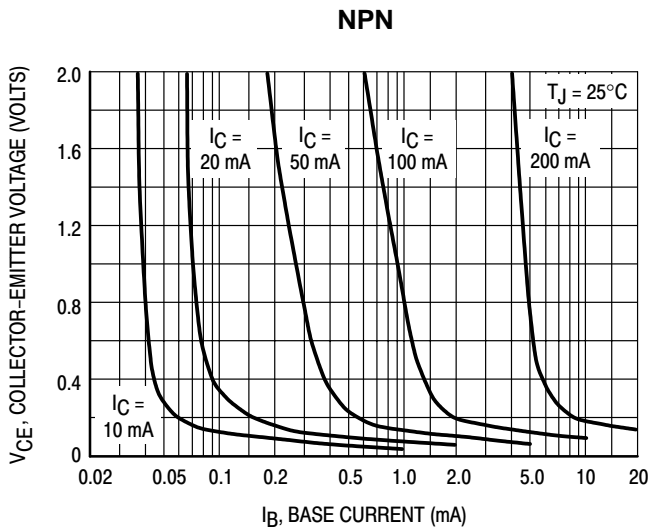


Figure 15. MPS8098/99 Collector Saturation Region

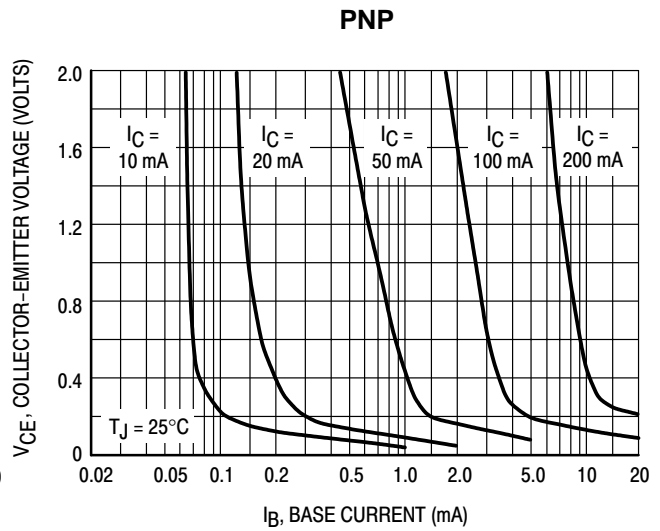


Figure 16. MPS8598/99 Collector Saturation Region

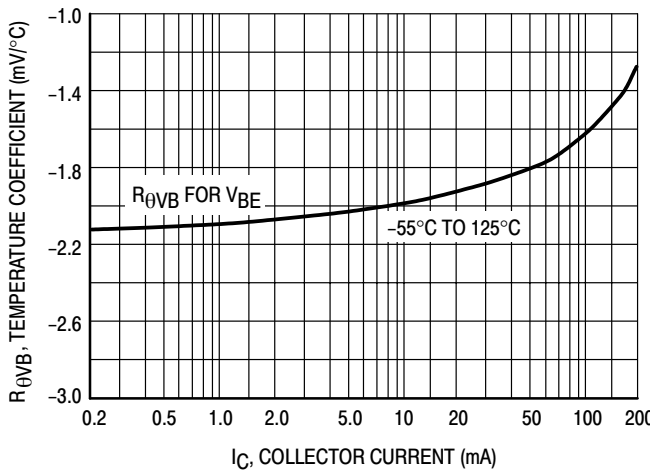


Figure 17. MPS8098/99 Base-Emitter Temperature Coefficient

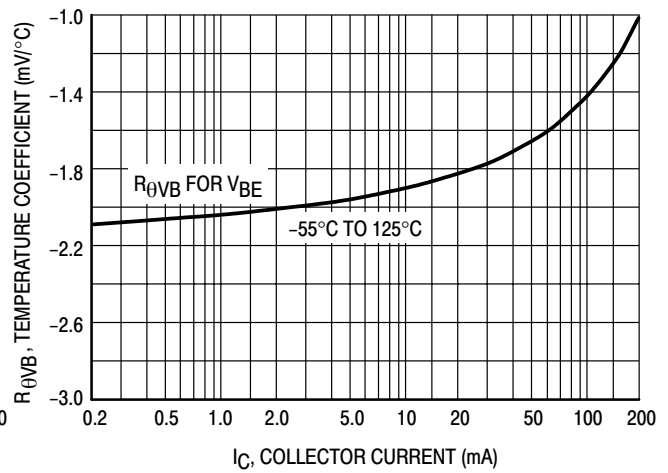
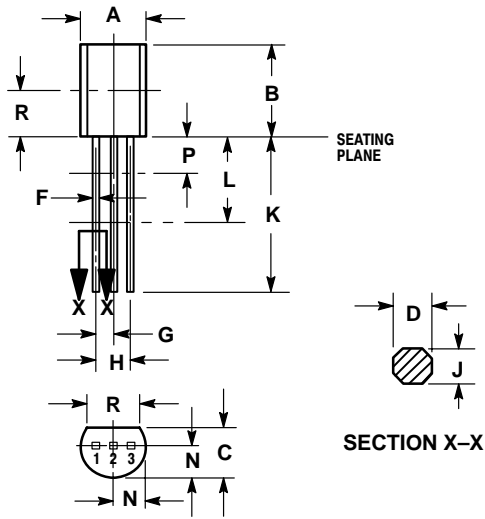


Figure 18. MPS8598/99 Base-Emitter Temperature Coefficient

NPN MPS8098 MPS8099 PNP MPS8598 MPS8599

PACKAGE DIMENSIONS

CASE 029-11
(TO-226AA)
ISSUE AD



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. DIMENSION F APPLIES BETWEEN P AND L. DIMENSIONS D AND J APPLY BETWEEN L AND K MINIMUM. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.175	0.205	4.44	5.21
B	0.290	0.310	7.37	7.87
C	0.125	0.165	3.18	4.19
D	0.018	0.021	0.457	0.533
F	0.016	0.019	0.407	0.482
G	0.045	0.055	1.15	1.39
H	0.095	0.105	2.42	2.66
J	0.018	0.024	0.46	0.61
K	0.500	---	12.70	---
L	0.250	---	6.35	---
N	0.080	0.105	2.04	2.66
P	---	0.100	---	2.54
R	0.135	---	3.43	---

- YLE 1:
PIN 1. EMITTER
2. BASE
3. COLLECTOR

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